Memory Module Specifications

KVR29S21S6/4

4GB 1Rx16 512M x 64-Bit PC4-2933 CL21 260-Pin SODIMM

DESCRIPTION

This document describes ValueRAM's KVR29S21S6/4 as a 512M x 64-bit (4GB) DDR4-2933 CL21 SDRAM (Synchronous DRAM), 1Rx16, memory module, based on four 512M x 16-bit FBGA components. The SPD is programmed to JEDEC standard latency DDR4-2933 timing of 21-21-21 at 1.2V. This 260-pin SODIMM uses gold contact fingers. The electrical and mechanical specifications are as follows:

FEATURES

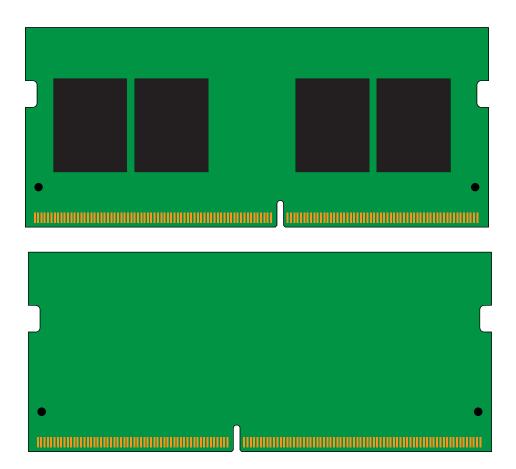
- Power Supply: VDD = 1.2V Typical
- VDDQ = 1.2V Typical
- VPP = 2.5V Typical
- VDDSPD = 2.2V to 3.6V
- Nominal and dynamic on-die termination (ODT) for data, strobe, and mask signals
- · Low-power auto self refresh (LPASR)
- Data bus inversion (DBI) for data bus
- On-die VREFDQ generation and calibration
- · Single-rank
- · On-board I2 serial presence-detect (SPD) EEPROM
- · 8 internal banks; 2 groups of 4 banks each
- Fixed burst chop (BC) of 4 and burst length (BL) of 8 via the mode register set (MRS)
- Selectable BC4 or BL8 on-the-fly (OTF)
- · Fly-by topology
- · Terminated control command and address bus
- PCB: Height 1.18" (30.00mm)
- · RoHS Compliant and Halogen-Free

SPECIFICATIONS

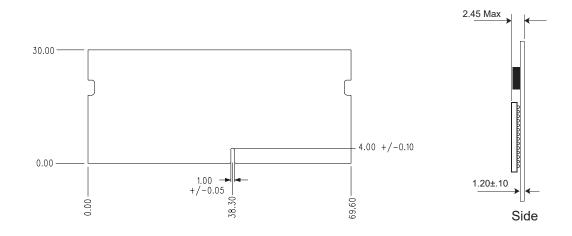
CL(IDD)	21 cycles
Row Cycle Time (tRCmin)	45.75ns(min.)
Refresh to Active/Refresh Command Time (tRFCmin)	350ns(min.)
Row Active Time (tRASmin)	32ns(min.)
	02110(11111.)
UL Rating	94 V - 0
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UL Rating	94 V - 0

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MODULE DIMENSIONS



All measurements are in millimeters. (Tolerances on all dimensions are ±0.12 unless otherwise specified)



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